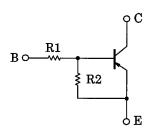
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

RN2967,RN2968,RN2969

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- Including two devices in US6 (ultra super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1967~RN1969

Equivalent Circuit and Bias Resistor Values



| Type No. | R1 (kΩ) | R2 (kΩ) |
|----------|---------|---------|
| RN2967 | 10 | 47 |
| RN2968 | 22 | 47 |
| RN2969 | 47 | 22 |

Unit: mm 2.1 ± 0.1 1.25±0.1 1.3 ± 0.1 0.65 1. EMITTER 1 2. EMITTER 2 3. BASE 2 (B2) 4. COLLECTOR 2 (C2) 5. BASE 1 (B1)6. COLLECTOR 1 (C1) **JEDEC JEITA TOSHIBA** 2-2J1B

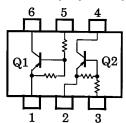
Weight: 6.8mg(typ.)

Equivalent Circuit (Top View)

Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

| Characterist | Symbol | Rating | Unit | | |
|-----------------------------|-------------|------------------|---------|----|--|
| Collector-base voltage | RN2967~2969 | V _{CBO} | -50 | V | |
| Collector-emitter voltage | KN2907~2909 | V _{CEO} | -50 | V | |
| | RN2967 | | -6 | V | |
| Emitter-base voltage | RN2968 | V_{EBO} | -7 | | |
| | RN2969 | | -15 | | |
| Collector current | | IC | -100 | mA | |
| Collector power dissipation | RN2967~2969 | P _C * | 200 | mW | |
| Junction temperature | RN2907~2909 | Tj | 150 | °C | |
| Storage temperature range | | T _{stg} | -55~150 | °C | |

^{*:} Total rating

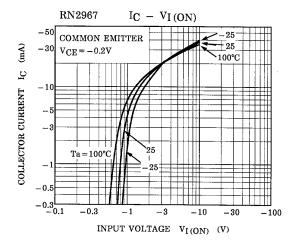


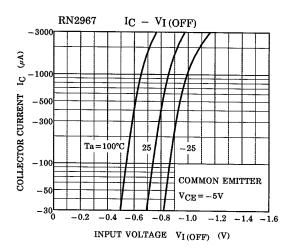


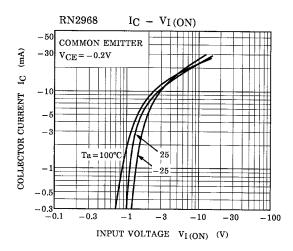
Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

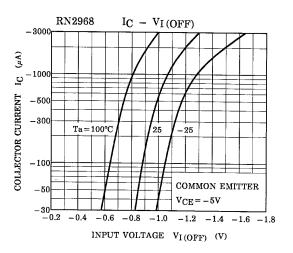
| Characteristic | | Symbol | Test Circuit | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------------|---------------|-----------------------|-----------------|---|--------|-------|--------|------|
| Collector cut-off current | RN2967~2969 — | I _{CBO} | _ | $V_{CB} = -50V$, $I_E = 0$ | _ | _ | -100 | nA |
| | | ICEO | _ | V _{CE} = -50V, I _B = 0 | _ | _ | -500 | |
| Emitter cut-off current | RN2967 | I _{EBO} | _ | V _{EB} = -6V, I _C = 0 | -0.081 | _ | -0.15 | mA |
| | RN2968 | | _ | V _{EB} = -7V, I _C = 0 | -0.078 | _ | -0.145 | |
| | RN2969 | | _ | V _{EB} = −15V, I _C = 0 | -0.167 | _ | -0.311 | |
| | RN2967 | h _{FE} | _ | V _{CE} = −5V, I _C = −10mA | 80 | _ | _ | _ |
| DC current gain | RN2968 | | _ | | 80 | _ | _ | |
| | RN2969 | | _ | | 70 | _ | _ | |
| Collector-emitter saturation voltage | RN2967~2969 | V _{CE} (sat) | _ | $I_C = -5mA$ $I_B = -0.25mA$ | _ | -0.1 | -0.3 | V |
| Input voltage (ON) | RN2967 | V _{I (ON)} | _ | V _{CE} = -0.2V I _C = -5mA | -0.7 | _ | -1.8 | ٧ |
| | RN2968 | | _ | | -1.0 | _ | -2.6 | |
| | RN2969 | | _ | | -2.2 | _ | -5.8 | |
| Input voltage (OFF) | RN2967 | V _{I (OFF)} | _ | V _{CE} = -5V I _C = -0.1mA | -0.5 | _ | -1.0 | V |
| | RN2968 | | _ | | -0.6 | _ | -1.16 | |
| | RN2969 | | _ | | -1.5 | _ | -2.6 | |
| Translation frequency | RN2967~2969 | fT | _ | V _{CE} =-10V I _C = -5mA | _ | 200 | _ | MHz |
| Collector output capacitance | RN2967~2969 | C _{ob} | _ | V _{CB} = -10V, I _E = 0, f = 1MHz | _ | 3 | 6 | pF |
| Input resistor | RN2967 | R1 | _ | _ | 7 | 10 | 13 | kΩ |
| | RN2968 | | _ | | 15.4 | 22 | 28.6 | |
| | RN2969 | | _ | | 32.9 | 47 | 61.1 | |
| Resistor ratio | RN2967 | R1/R2 | _ | _ | 0.191 | 0.213 | 0.232 | _ |
| | RN2968 | | _ | | 0.421 | 0.468 | 0.515 | |
| | RN2969 | | _ | | 0.09 | 2.14 | 2.35 | |

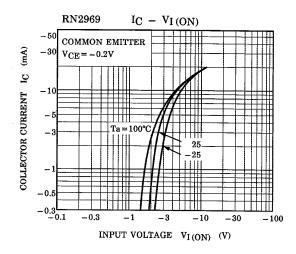
(Q1, Q2 Common)

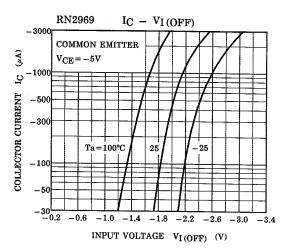








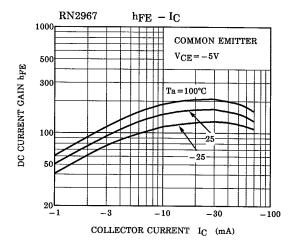


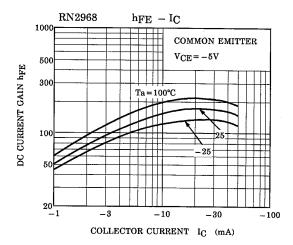


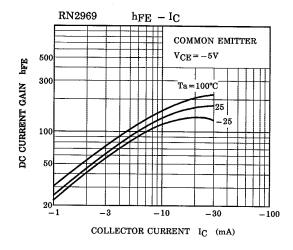
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(Q1, Q2 Common)

TOSHIBA









| Type Name | Marking |
|-----------|-------------------|
| RN2967 | Type Name YY H |
| RN2968 | Type Name YYI HHH |
| RN2969 | Type Name YY J |

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